Lesson Plan Branch: ECS

Semester: I

Year: 2022-23

Course Title: Engineering Physics - I	SEE: 2 Hours – Theory
Total Contact Hours: 26 Hours	Duration of SEE: 2 Hrs
SEE Marks: 60 (Theory) + 15 (IA)	
Lesson Plan Author: Dileep Chandra. C	Date:
Checked By:	Date:

	Syllabus			
Module	Detailed Contents	Hrs.		
	QUANTUM PHYSICS			
	(Prerequisites: Dual nature of radiation, Photoelectric effect Matter waves-wave nature of particles, de-Broglie			
	relation, Davisson-Germer experiment)			
01	De Broglie hypothesis of matter waves; properties of matter waves; wave packet, phase velocity and group			
	velocity; Wave function; Physical interpretation of wave function; Heisenberg uncertainty principle;			
	nonexistence of electron in nucleus; Schrodinger's time dependent wave equation; time independent wave			
	equation; Particle trapped in one dimensional infinite potential well, Quantum Computing.			
	SOLID STATE PHYSICS - CRYSTALLOGRAPHY			
	(Prerequisites: Crystal Physics (Unit cell, Space lattice, Crystal structure,			
02	Simple Cubic, Body Centered Cubic, Face Centered Cubic, Diamond Structure, Production of X-rays)	03		
	Miller indices; interplanar spacing; X-ray diffraction and Bragg's law;			
	Determination of Crystal structure using Bragg's diffractometer;			
	SOLID STATE PHYSICS - SEMICONDUCTORS			
03	(Prerequisites: Intrinsic and extrinsic semiconductors, Energy bands in	06		
	conductors, semiconductors and insulators, Semiconductor diode, I-V			

	characteristics in forward and reverse bias)	
	Direct & indirect band gap semiconductor; Fermi level; Fermi dirac distribution; Fermi energy level in intrinsic &	
	extrinsic semiconductors; effect of impurity concentration and temperature on fermi level; mobility, current	
	density; Hall Effect; Fermi Level diagram for p-n junction (unbiased, forward bias, reverse bias); Applications of	
	semiconductors: LED, Zener diode, Photovoltaic cell.	
	OPTICS-I	
	(Prerequisites: Wave front and Huygen's principle, reflection and refraction, Interference by division of wave	
	front, Youngs double slit experiment)	
	Interference by division of amplitude, Interference in thin film of constant	
)4	thickness due to reflected and transmitted light; origin of colours in thin film;	06
	Wedge shaped film; Newton's rings.	
	Applications of interference - Determination of thickness of very thin wire or foil; determination of refractive index	
	of liquid; wavelength of incident light; radius of curvature of lens; testing of surface flatness; Anti-reflecting films	
	and Highly reflecting film.	
	SUPERCONDUCTORS AND SUPERCAPACITORS	
	(Prerequisites: Electric current, flow of electric charges in a metallic conductor, drift velocity, mobility and their	
	relation with electric current, Ohm's law, electrical resistance, V-I characteristics (linear and non-linear),	
	electrical resistivity and conductivity temperature dependence of resistance)	
05	Superconductors: Critical temperature, critical magnetic field, Meissner's effect, Type I and Type II and high	02
	Tc superconductors;	
	Super capacitors: Principle, construction, types, materials and applications,	
	comparison with capacitor and batteries: Energy density, Power density,	
	ENGINEERING MATERIALS AND APPLICATIONS	
06		02

(Prerequisites: Paramagnetic materials, diamagnetic materials, ferromagnetic materials, crystal physics,
Conductors and insulators, free charges and bound charges inside a conductor. Dielectrics and electric
polarisation, capacitors and capacitance)
Liquid crystals: Nematic, Smectic and cholesteric phases, Liquid crystal display.
Multiferroics: Type I & Type II multiferroics and applications, Magnetoresistive Oxides: Magnetoresistance,
GMR and CMR materials,
introduction to spintronics.

Course Outcomes (CO):

On successful completion of course learner will be able to:

FEC102.1	Illustrate the fundamentals of quantum mechanics and its application.
FEC102.2	Illustrate the knowledge of crystal planes, X-ray diffraction and its application.
FEC102.3	Illustrate the knowledge of Fermi level in semiconductors and applications of
	semiconductors in electronic devices.
FEC102.4	Illustrate the knowledge of interference in thin films and its various applications.
FEC102.5	Illustrate the basic knowledge of superconductors and supercapacitors.
FEC102.6	Illustrate the knowledge of engineering materials and applications.

CO-PO Mapping: (BL – Blooms Taxonomy, C – Competency, PI – Performance Indicator)

СО	BL	C	PI	PO	Mapping
FEC102.1	3	1.2	1.2.1	1	3
FEC102.2	3	1.2	1.2.1	1	3
FEC102.3	3	1.2	1.2.1	1	3
FEC102.4	3	1.2	1.2.1	1	3
FEC102.5	2	1.2	1.2.1	1	3
FEC102.6	3	1.2	1.2.1	1	3

	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12
FEC102.1	3											
FEC102.2	3											
FEC102.3	3											
FEC102.4	3											
FEC102.5	3											
FEC102.6	3											

CO Measurement Weightages for Tools:

	0		
Class Test	Tutorial	End Semester	Course Exit
		Exam	Survey
20%	20%	60%	
20%	20%	60%	
20%	20%	60%	
20%	20%	60%	
	20%	80%	
	20% 20% 20%	Class Test Tutorial 20% 20% 20% 20% 20% 20% 20% 20% 20% 20%	Class Test Tutorial End Semester 20% 20% 60% 20% 20% 60% 20% 20% 60% 20% 20% 60% 20% 20% 60% 20% 20% 60%

Attainment Calculations:

CO1_attainment = [0.8 * (0.6 * ESE + 0.2 * CT + 0.2 * TU) + 0.2 * CES] CO2_attainment = [0.8 * (0.6 * ESE + 0.2 * CT + 0.2 * TU) + 0.2 * CES] CO3_attainment = [0.8 * (0.6 * ESE + 0.2 * CT + 0.2 * TU) + 0.2 * CES] CO4_attainment = [0.8 * (0.6 * ESE + 0.2 * CT + 0.2 * TU) + 0.2 * CES] CO5 attainment = [0.8 * (0.8 * ESE + 0.2 * TU) + 0.2 * CES]

Lecture Plan:

No.	Name of the Topic	Planned Date	Executed Date	Mapped CO	Remarks			
Mod	ule: 2 SOLIDSTATE PHYSICS - CRYSTALLOGRAPHY (03 hrs)							
1Introduction to crystallography; unit cellS, Diamond Structure16-11-202216-11-2022								
2	2 Miller indices of crystallographic planes & directions; 17-11-2022 17-11-2022							
3 Interplanar spacing, X-ray diffraction and Bragg's law; 22-11-2022 22-11-2022 FEC.								
4	Determination of Crystal structure using Bragg's diffractometer;	24-11-2022	24-11-2022					
Mod	ule: 3 SOLIDSTATE PHYSICS - SEMICONDUCTORS (06 hrs)							
1	Classification of semiconductors (direct & indirect band gap, elemental	30-11-2022	30-11-2022					
2	Conductivity, mobility, current density (drift & diffusion) in semiconductors (n type and p type);	06-12-2022	06-12-2022		Lectures taken by Dr. S.S. Rathod			
3	Fermi Dirac distribution function; Fermi energy level in intrinsic & extrinsic semiconductors;	07-12-2022	07-12-2022	CO 3				
4	effect of impurity concentration and temperature on fermi level;	13-12-2022	13-12-2022	FEC102.3				
5	Fermi Level diagram for p-n junction (unbiased, forward bais, reverse bias);	13-12-2022	13-12-2022					
6	Hall Effect, Numericals	20-12-2022	20-12-2022					
7	Applications of semiconductors: Rectifier diode, LED, Zener diode, Photo diode,	20-12-2022	20-12-2022					
Mod	ule 4 OPTICS - I (05 hrs)							
1	Interference by division of amplitude, Interference in thin film of constant thickness due to reflected and transmitted light;	25/11/2022	25/11/2022					
2	Wedge shaped film; Newton's rings	29/11/2022	29/11/2022					
3	Numericals on Wedge shaped film; Newton's rings	1/12/2022	1/12/2022	CO4				
4	Applications of interference- Determination of thickness of very thin wire or foil; determination of refractive index of liquid; wavelength of incident light;	2/12/2022	2/12/2022	FEC102.4				
5	Applications of interference- radius of curvature of lens; testing of surface flatness; Anti-reflecting films and Highly reflecting film.	6/12/2022	6/12/2022					
	1 2 3 4 Mod 1 2 3 4 5 6 7 Mod 1 2 3 3 4 5	 Miller indices of crystallographic planes & directions; Interplanar spacing, X-ray diffraction and Bragg's law; Determination of Crystal structure using Bragg's diffractometer; Module: 3 SOLIDSTATE PHYSICS - SEMICONDUCTORS (06 hrs) Classification of semiconductors (direct & indirect band gap, elemental Conductivity, mobility, current density (drift & diffusion) in semiconductors (n type and p type); Fermi Dirac distribution function; Fermi energy level in intrinsic & extrinsic semiconductors; effect of impurity concentration and temperature on fermi level; Fermi Level diagram for p-n junction (unbiased, forward bais, reverse bias); Hall Effect, Numericals Applications of semiconductors: Rectifier diode, LED, Zener diode, Photo diode, Module 4 OPTICS - I (05 hrs) Interference by division of amplitude, Interference in thin film of constant thickness due to reflected and transmitted light; Wedge shaped film; Newton's rings Numericals on Wedge shaped film; Newton's rings Applications of interference- Determination of thickness of very thin wire or foil; determination of refractive index of liquid; wavelength of incident light; Applications of interference- radius of curvature of lens; testing of surface flatness; 	1Introduction to crystallography; unit cellS, Diamond Structure16-11-20222Miller indices of crystallographic planes & directions;17-11-20223Interplanar spacing, X-ray diffraction and Bragg's law;22-11-20224Determination of Crystal structure using Bragg's diffractometer;24-11-2022Module: 3 SOLIDSTATE PHYSICS - SEMICONDUCTORS (06 hrs)11Classification of semiconductors (direct & indirect band gap, elemental30-11-20222Conductivity, mobility, current density (drift & diffusion) in semiconductors (n type and p type);06-12-20223Fermi Dirac distribution function; Fermi energy level in intrinsic & extrinsic semiconductors;07-12-20224effect of impurity concentration and temperature on fermi level;13-12-20225Fermi Level diagram for p-n junction (unbiased, forward bais, reverse bias);13-12-20227Applications of semiconductors: Rectifier diode, LED, Zener diode, Photo diode,20-12-20227Mauericals on Semiconductors: Rectifier diode, LED, Zener diode, Photo diode,25/11/20222Wedge shaped film; Newton's rings1/12/20223Numericals on Wedge shaped film; Newton's rings1/12/20224Applications of interference- Determination of thickness of very thin wire or foil; determination of refractive index of liquid; wavelength of incident light;2/12/20225Applications of interference- radius of curvature of lens; testing of surface flatness; Anti-reflecting films and Highly reflecting film.6/12/2022	1Introduction to crystallography; unit cellS, Diamond Structure16-11-202216-11-20222Miller indices of crystallographic planes & directions;17-11-202217-11-20223Interplanar spacing, X-ray diffraction and Bragg's law;22-11-202222-11-20224Determination of Crystal structure using Bragg's diffractometer;24-11-202224-11-20224Determination of Crystal structure using Bragg's diffractometer;24-11-202224-11-20224Determination of semiconductors (direct & indirect band gap, elemental30-11-202230-11-20227Conductivity, mobility, current density (drift & diffusion) in semiconductors (n type and p type);06-12-202206-12-20223Fermi Dirac distribution function; Fermi energy level in intrinsic & extrinsic semiconductors;07-12-202213-12-20224effect of impurity concentration and temperature on fermi level;13-12-202213-12-20225Fermi Level diagram for p-n junction (unbiased, forward bais, reverse bias);13-12-202220-12-20227Applications of semiconductors: Rectifier diode, LED, Zener diode, Photo diode, due to reflected and transmitted light;25/11/202225/11/20222Wedge shaped film; Newton's rings1/12/20221/12/20222/11/20223Numericals on Wedge shaped film; Newton's rings1/12/20222/12/20224Applications of interference- Determination of thickness of very thin wire or foil; determination of refractive index of liquid; wavelength of incident light;2/12/20222/12/20223Numerical	1Introduction to crystallography; unit cells, Diamond Structure16-11-202216-11-202216-11-2022CO22Miller indices of crystallographic planes & directions;17-11-202217-11-202222-11-2022223Interplanar spacing, X-ray diffraction and Bragg's law;22-11-202222-11-202224-11-202224-11-20224Determination of Crystal structure using Bragg's diffractometer;24-11-202224-11-202224-11-202224-11-20224Determination of Semiconductors (direct & indirect band gap, elemental30-11-202230-11-202206-12-202206-12-20226Conductivity, mobility, current density (drift & diffusion) in semiconductors (n type and p type);06-12-202207-12-202207-12-202207-12-20223Fermi Dirac distribution function; Fermi energy level in intrinsic & extrinsic semiconductors;07-12-202207-12-202207-12-20224effect of impurity concentration and temperature on fermi level;13-12-202213-12-202213-12-20225Fermi Level diagram for p-n junction (unbiased, forward bais, reverse bias);13-12-202220-12-202220-12-20226Hall Effect, Numericals20-12-202220-12-202220-12-202220-12-20227Applications of semiconductors: Rectifier diode, LED, Zener diode, Photo diode,25/11/202225/11/20221Interference by division of amplitude, Interference in thin film of constant thickness25/11/202225/11/20223Numericals on Wedge shaped film; Newton's rings1/12/20221/12/20222/			

17	1Introduction, Wave particle duality; de Broglie wavelength; experimental verification of de Broglie theory;9/12/20229/12/2022							
18	2 properties of matter waves; wave packet, phase velocity and group velocity; 13/12/2022 13/12/2022							
19	3Wave function; Physical interpretation of wave function;14/12/202214/12/2022							
20	4 Heisenberg's uncertainty principle; Electron diffraction experiment, Applications of uncertainty principle; Electron diffraction experiment, Applications of 15/12/2022 15/12/2022 FEC102.							
21	5	Schrodinger's time dependent wave equation; time independent wave equation;	16/12/2022	16/12/2022				
22	6	Motion of free particle; Particle trapped in one dimensional infinite potential well.	27/12/2022	27/12/2022				
23	7	Numerical problems	29/12/2022	29/12/2022				
	Мо	dule 5 SUPERCONDUCTORS & SUPER CAPACITORS (03 Hrs)	1		•			
24	1	Superconductors: Critical temperature, critical magnetic field, Meissner's effect	30-12-2022	30-12-2022				
25	2	Type I and Type II and high Tc superconductors;	03-01-2023	17-01-2023	CO5			
26			FEC102.5					
	Мо	dule 6 ENGINEERING MATERIALS & APPLICATIONS (02Hrs)	-1	I	•			
27	1	Liquid crystals: Nematic, Smectic and cholesteric phases, Liquid crystal display. Multiferroics: Type I & Type II multiferroics and applications,			CO6			
28	2	Magnetoresistive Oxides: Magnetoresistance, GMR and CMR materials.		FEC102.6	excluded			

Reference Books:

- 1. A text book of Engineering Physics-Avadhanulu & Kshirsagar, S. Chand
- 2. A textbook of Optics N. Subramanyam and Brijlal, S.Chand
- 3. Fundamentals of optics by Jenkins and White, McGrawHill
- 4. Solid State Electronic Devices- B. G. Streetman, Prentice Hall Publisher
- 5. Modern Engineering Physics Vasudeva, S.Chand
- 6. Concepts of Modern Physics- Arther Beiser, Tata McGraw Hill
- 7. A text book of Engineering Physics-Avadhanulu & Kshirsagar, S. Chand
- 8. A textbook of Optics N. Subramanyam and Brijlal, S.Chand
- 9. Fundamentals of optics by Jenkins and White, McGrawHill
- 10. Solid State Electronic Devices- B. G. Streetman, Prentice Hall Publisher
- 11. Modern Engineering Physics Vasudeva, S.Chand

- 12. Concepts of Modern Physics- Arther Beiser, Tata McGraw Hill
- 13. A Text Book of Engineering Physics, S. O. Pillai, New Age International Publishers.
- 14. Introduction to Solid State Physics- C. Kittle, John Wiley& Sons publisher
- 15. Ultracapacitors: The future of energy storage- R.P Deshpande, McGraw Hill
- 16. Advanced functional materials Ashutosh Tiwari, Lokman Uzun, Scrivener Publishing

Evaluation Scheme

CIE Scheme Internal Assessment: 15 (Average of two tests)

Internal Assessment Scheme

Module		Lecture	N	o. of questions in		No. of questions in SEE
	Module	Hours	Test 1	Test 2	Test 3*	No. of questions in SEE
1	SOLIDSTATE PHYSICS - CRYSTALLOGRAPHY	4	7			
2	SOLIDSTATE PHYSICS - SEMICONDUCTORS	6	8			
3	OPTICS - I	5		8		
4	QUANTUM MECHANICS	7		7		
5	SUPERCONDUCTORS & SUPER CAPACITORS	3				
6	ENGINEERING MATERIALS & APPLICATIONS					

Note: Four to six questions will be set in the Test paper

Verified by:

Programme Coordinator

Subject Expert